

## Switchmode Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching Mode Power Supplies such as adapters, Photovoltaic Solar cell protection, free-wheeling and polarity protection diodes.

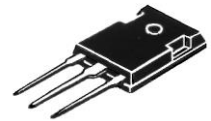
### Features

- \* Ultra Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Low Power Loss & High efficiency.
- \* 150°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- \* Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives

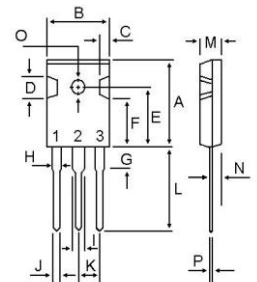


### SCHOTTKY BARRIER RECTIFIERS

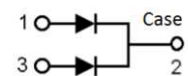
**60 AMPERES  
60VOLTS**



**TO-3P**



DIM	MILLIMETERS	
	MIN	MAX
A	20.80	21.80
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.50	15.50
F	11.20	13.20
G	3.75	4.35
H	1.90	2.30
I	2.90	3.30
J	1.00	1.40
K	5.26	5.66
L	19.50	20.50
M	4.68	5.36
N	2.30	2.60
O	3.45	3.85
P	0.48	0.72



### MAXIMUM RATINGS

Characteristic	Symbol	S60D60CL	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	42	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_R$ ),	$I_{F(AV)}$	30 60	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	$I_{FSM}$	350	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	°C

### ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage ( per diode ) ( $I_F = 30$ Amp $T_C = 25^\circ C$ ) ( $I_F = 30$ .Amp $T_C = 125^\circ C$ )	$V_F$	---	0.57 0.56	0.65 ---	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^\circ C$ ) ( Rated DC Voltage, $T_C = 125^\circ C$ )	$I_R$	---	0.13 50	0.30 ---	mA

FIG-1 FORWARD CURRENT DERATING CURVE

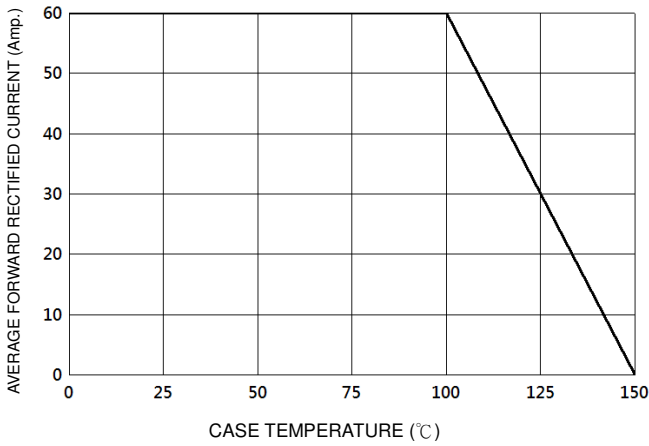


FIG-2 TYPICAL FORWARD CHARACTERISTICS

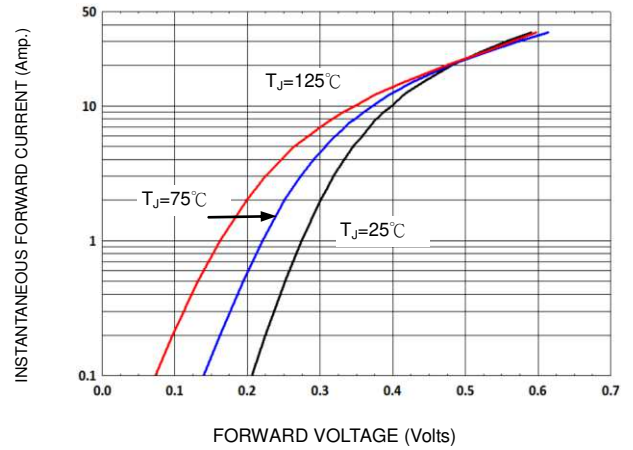


FIG-3 TYPICAL REVERSE CHARACTERISTICS

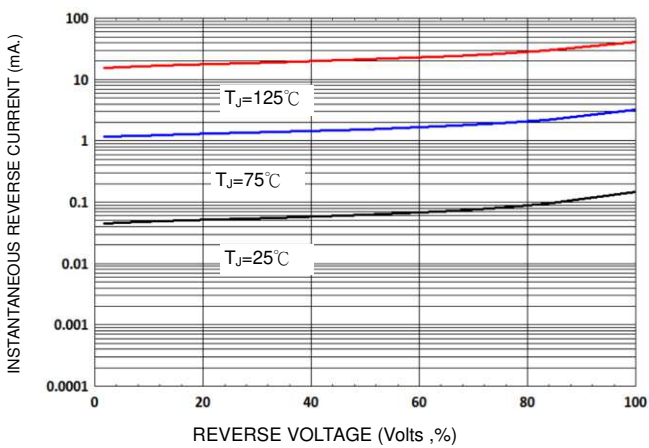


FIG-4 TYPICAL JUNCTION CAPACITANCE

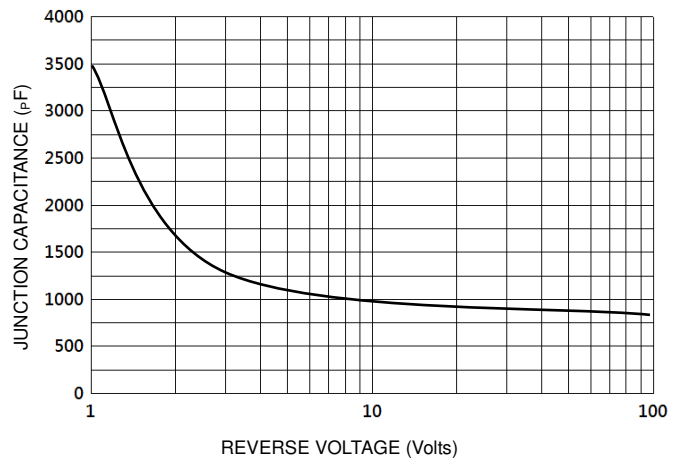
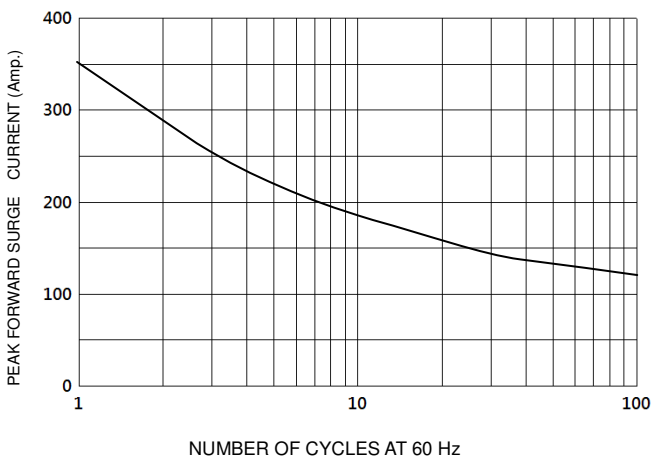


FIG-5 PEAK FORWARD SURGE CURRENT



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